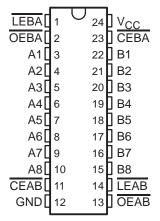
### SN74LVC543A OCTAL REGISTERED TRANSCEIVER WITH 3-STATE OUTPUTS

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- **EPIC** ™ (Enhanced-Performance Implanted **CMOS) Submicron Process**
- Typical V<sub>OLP</sub> (Output Ground Bounce) < 0.8 V at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot) > 2 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- **Power Off Disables Outputs, Permitting** Live Insertion
- **Supports Mixed-Mode Signal Operation on** All Ports (5-V Input/Output Voltage With 3.3-V V<sub>CC</sub>)
- Latch-Up Performance Exceeds 250 mA Per **JESD 17**
- **Package Options Include Plastic** Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) **Packages**

#### **DB. DW. OR PW PACKAGE** (TOP VIEW)



### description

This octal registered transceiver is designed for 1.65-V to 3.6-V  $V_{CC}$  operation.

The SN74LVC543A contains two sets of D-type latches for temporary storage of data flowing in either direction. Separate latch-enable (LEAB or LEBA) and output-enable (OEAB or OEBA) inputs are provided for each register to permit independent control in either direction of data flow.

The A-to-B enable (CEAB) input must be low to enter data from A or to output data from B. If CEAB is low and LEAB is low, the A-to-B latches are transparent; a subsequent low-to-high transition of LEAB places the A latches in the storage mode. With  $\overline{CEAB}$  and  $\overline{OEAB}$  both low, the 3-state B outputs are active and reflect the data present at the output of the A latches. Data flow for B to A is similar to that of A to B, but uses  $\overline{CEBA}$ ,  $\overline{LEBA}$ , and OEBA.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

The SN74LVC543A is characterized for operation from -40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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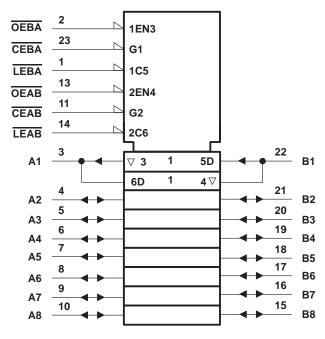
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#### **FUNCTION TABLE**†

|      | INPUTS |      |   |                  |  |  |  |  |  |
|------|--------|------|---|------------------|--|--|--|--|--|
| CEAB | LEAB   | OEAB | Α | В                |  |  |  |  |  |
| Н    | Х      | Х    | Χ | Z                |  |  |  |  |  |
| Х    | X      | Н    | Χ | Z                |  |  |  |  |  |
| L    | Н      | L    | Χ | в <sub>0</sub> ‡ |  |  |  |  |  |
| L    | L      | L    | L | L                |  |  |  |  |  |
| L    | L      | L    | Н | Н                |  |  |  |  |  |

<sup>†</sup> A-to-B data flow is shown; B-to-A flow control is the same except that it uses CEBA, LEBA, and OEBA.

### logic symbol§

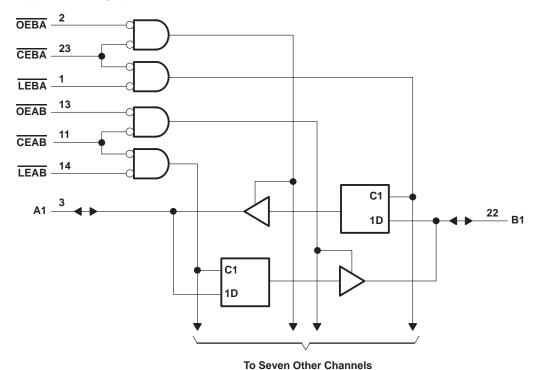


§ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



<sup>‡</sup>Output level before the indicated steady-state input conditions were established

### logic diagram (positive logic)



### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

| Supply voltage range, V <sub>CC</sub>  |                                  |
|--|----------------------------------|
| Voltage range applied to any output in the high-impedance or power-off state, V <sub>O</sub> | –0.5 V to 6.5 V                  |
| (see Note 1)   | –0.5 V to 6.5 V                  |
| Voltage range applied to any output in the high or low state, VO                             |                                  |
| (see Notes 1 and 2)  | 0.5 V to V <sub>CC</sub> + 0.5 V |
| Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)                                    | –50 mA                           |
| Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)                                   | –50 mA                           |
| Continuous output current, I <sub>O</sub>  | ±50 mA                           |
| Continuous current through V <sub>CC</sub> or GND  | ±100 mA                          |
| Package thermal impedance, θ <sub>JA</sub> (see Note 3): DB package                          | 104°C/W                          |
| DW package   | 81°C/W                           |
| PW package   | 120°C/W                          |
| Storage temperature range, T <sub>stq</sub>  | –65°C to 150°C                   |

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

- 2. The value of V<sub>CC</sub> is provided in the recommended operating conditions table.
- 3. The package thermal impedance is calculated in accordance with JESD 51.



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### recommended operating conditions (see Note 4)

|                          |                                    |  | MIN                  | MAX                  | UNIT |  |  |
|--------------------------|------------------------------------|--|----------------------|----------------------|------|--|--|
| V                        | Supply voltage                     | Operating                                  | 1.65                 | 3.6                  | V    |  |  |
| VCC                      | Supply voltage                     | Data retention only                        | 1.5                  |                      | V    |  |  |
|                          |                                    | V <sub>CC</sub> = 1.65 V to 1.95 V         | 0.65×V <sub>CC</sub> |                      |      |  |  |
| $V_{IH}$                 | /IH High-level input voltage       | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | 1.7                  |                      | V    |  |  |
|                          |                                    | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | 2                    |                      |      |  |  |
|                          |                                    | V <sub>CC</sub> = 1.65 V to 1.95 V         |                      | 0.35×V <sub>CC</sub> |      |  |  |
| $V_{IL}$                 | Low-level input voltage            | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ |                      | 0.7                  | V    |  |  |
|                          |                                    | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ |                      | 0.8                  |      |  |  |
| ٧ <sub>I</sub>           | Input voltage                      |  | 0                    | 5.5                  | V    |  |  |
| .,                       | Output voltage                     | High or low state                          | 0                    | Vcc                  | V    |  |  |
| VO                       |                                    | 3 state                                    | 0                    | 5.5                  | V    |  |  |
|                          |                                    | V <sub>CC</sub> = 1.65 V                   |                      | -4                   |      |  |  |
| 1                        | High lavel autout august           | V <sub>CC</sub> = 2.3 V                    |                      | -8                   | A    |  |  |
| ЮН                       | High-level output current          | V <sub>CC</sub> = 2.7 V                    |                      | -12                  | mA   |  |  |
|                          |                                    | V <sub>CC</sub> = 3 V                      |                      | -24                  |      |  |  |
| I <sub>OL</sub> Low-leve |                                    | V <sub>CC</sub> = 1.65 V                   |                      | 4                    |      |  |  |
|                          | Lave laved authors average         | V <sub>CC</sub> = 2.3 V                    |                      | 8                    | A    |  |  |
|                          | Low-level output current           | V <sub>CC</sub> = 2.7 V                    |                      | 12                   | mA   |  |  |
|                          |                                    | V <sub>CC</sub> = 3 V                      |                      | 24                   |      |  |  |
| Δt/Δν                    | Input transition rise or fall rate | •  | 0                    | 10                   | ns/V |  |  |
| TA                       | Operating free-air temperature     |  | -40                  | 85                   | °C   |  |  |

NOTE 4: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PA   | RAMETER   | TEST CONDITIONS                         |                           | VCC                 | MIN | TYP† | MAX  | UNIT |  |
|--|---|---|---------------------------|---------------------|-----|------|------|------|--|
|  |   | I <sub>OH</sub> = -100 μA               | 1.65 V to 3.6 V           | V <sub>CC</sub> -0. | .2  |      |      |      |  |
|  |   | I <sub>OH</sub> = -4 mA                 | 1.65 V                    | 1.2                 |     |      |      |      |  |
| \ <sub>\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\</sub> |   | I <sub>OH</sub> = -8 mA                 |                           | 2.3 V               | 1.7 |      |      | V    |  |
| VOH  |   | I <sub>OH</sub> = -12 mA                |                           | 2.7 V               | 2.2 |      |      | V    |  |
|  |   | IOH = -12 IIIA                          |                           | 3 V                 | 2.4 |      |      |      |  |
|  |   | I <sub>OH</sub> = -24 mA                |                           | 3 V                 | 2.2 |      |      |      |  |
|  |   | I <sub>OL</sub> = 100 μA                |                           | 1.65 V to 3.6 V     |     |      | 0.2  |      |  |
|  |   | I <sub>OL</sub> = 4 mA                  | 1.65 V                    |                     |     | 0.45 | V    |      |  |
| VOL  |   | I <sub>OL</sub> = 8 mA                  | 2.3 V                     |                     |     | 0.7  |      |      |  |
|  |   | I <sub>OL</sub> = 12 mA                 | 2.7 V                     |                     |     | 0.4  |      |      |  |
|  |   | I <sub>OL</sub> = 24 mA                 |                           | 3 V                 |     |      | 0.55 |      |  |
| Ц  | Control inputs  | V <sub>I</sub> = 0 to 5.5 V             |                           | 3.6 V               |     |      | ±5   | μΑ   |  |
| l <sub>off</sub>                                 |   | $V_I$ or $V_O = 5.5 V$                  |                           | 0                   |     |      | ±10  | μΑ   |  |
| loz‡   |   | V <sub>O</sub> = 0 to 5.5 V             |                           | 3.6 V               |     |      | ±10  | μΑ   |  |
| 1  |   | V <sub>I</sub> = V <sub>CC</sub> or GND | 1- 0                      | 261/                |     |      | 10   | ^    |  |
| ICC  |   | 3.6 V ≤ V <sub>I</sub> ≤ 5.5 V§         | IO = 0                    | 3.6 V               |     |      | 10   | μΑ   |  |
| Δlcc   | $\Delta I_{CC}$ One input at $V_{CC} - 0.6 \text{ V}$ , Other inputs at $V_{CC}$ or GND |   | at V <sub>CC</sub> or GND | 2.7 V to 3.6 V      |     |      | 500  | μΑ   |  |
| Ci   | Control inputs  | V <sub>I</sub> = V <sub>CC</sub> or GND |                           | 3.3 V               |     | 4.5  |      | pF   |  |
| C <sub>io</sub>                                  | A or B ports  | $V_O = V_{CC}$ or GND                   |                           | 3.3 V               |     | 7.5  |      | pF   |  |

# timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

|                 |                                    | V <sub>CC</sub> = |     | V <sub>CC</sub> = | 2.5 V<br>2 V | VCC = | 2.7 V | V <sub>CC</sub> = ± 0.3 | 3.3 V<br>3 V | UNIT |
|-----------------|------------------------------------|-------------------|-----|-------------------|--------------|-------|-------|-------------------------|--------------|------|
|                 |                                    | MIN               | MAX | MIN               | MAX          | MIN   | MAX   | MIN                     | MAX          |      |
| t <sub>W</sub>  | Pulse duration                     | ¶                 |     | ¶                 |              | 3.3   |       | 3.3                     |              | ns   |
| t <sub>su</sub> | Setup time, data before LE↑ or CE↑ | ¶                 |     | ¶                 |              | 1.6   |       | 1.6                     |              | ns   |
| t <sub>h</sub>  | Hold time, data after LE↑ or CE↑   | 1                 |     | ¶                 |              | 2.1   |       | 2.1                     |              | ns   |

This information was not available at the time of publication.

<sup>†</sup> All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C. ‡ For I/O ports, the parameter  $I_{OZ}$  includes the input leakage current.

<sup>§</sup> This applies in the disabled state only.

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# switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

| PARAMETER        | FROM<br>(INPUT) | TO<br>(OUTPUT) | V <sub>CC</sub> = | 1.8 V<br>5 V | V <sub>CC</sub> = | 2.5 V<br>2 V | VCC = | 2.7 V | V <sub>CC</sub> = | 3.3 V<br>3 V | UNIT |
|------------------|-----------------|----------------|-------------------|--------------|-------------------|--------------|-------|-------|-------------------|--------------|------|
|                  | (INFOT)         | (001701)       | MIN               | MAX          | MIN               | MAX          | MIN   | MAX   | MIN               | MAX          |      |
| + .              | A or B          | B or A         | †                 | †            | †                 | †            |       | 8     | 1                 | 7            | ns   |
| <sup>t</sup> pd  | LE              | BUIA           | †                 | †            | †                 | †            |       | 9.5   | 1.2               | 8.5          | 115  |
|                  | ŌĒ              | A or B         | †                 | †            | †                 | †            |       | 9.2   | 1.3               | 7.7          | no   |
| <sup>t</sup> en  | CE              |                | †                 | †            | †                 | †            |       | 9.3   | 1.3               | 8            | ns   |
| <sup>t</sup> dis | ŌĒ              | A == D         | †                 | †            | †                 | †            |       | 7.5   | 1                 | 7            | no   |
|                  | CE              | A or B         | †                 | †            | †                 | †            |       | 7.5   | 1                 | 7            | ns   |

<sup>†</sup> This information was not available at the time of publication.

## operating characteristics, $T_A = 25^{\circ}C$

| PARAMETER       |                               |                  | TEST<br>CONDITIONS | V <sub>CC</sub> = 1.8 V<br>± 0.15 V | V <sub>CC</sub> = 2.5 V<br>± 0.2 V | V <sub>CC</sub> = 3.3 V<br>± 0.3 V | UNIT |
|-----------------|-------------------------------|------------------|--------------------|-------------------------------------|------------------------------------|------------------------------------|------|
|                 |                               | CONDITIONS       | TYP                | TYP                                 | TYP                                |                                    |      |
| C <sub>pd</sub> | Power dissipation capacitance | Outputs enabled  | f = 10 MHz         | †                                   | †                                  | 49                                 | pF   |
| Opa             | per transceiver               | Outputs disabled | I = IU MIHZ        | †                                   | †                                  | 6                                  | h.   |

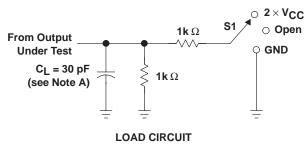
<sup>†</sup> This information was not available at the time of publication.



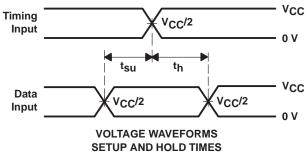
**VCC** 

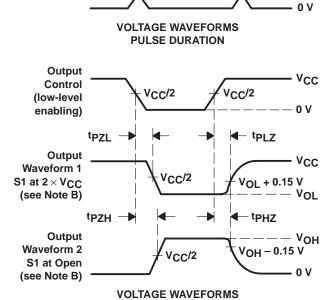
V<sub>CC</sub>/2

# PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$



| TEST            | S1                |
|-----------------|-------------------|
| t <sub>pd</sub> | Open              |
| tPLZ/tPZL       | 2×V <sub>CC</sub> |
| tPHZ/tPZH       | Open              |

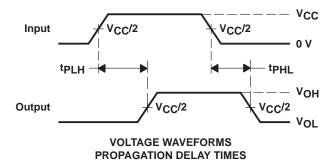




**ENABLE AND DISABLE TIMES** 

V<sub>CC</sub>/2

Input

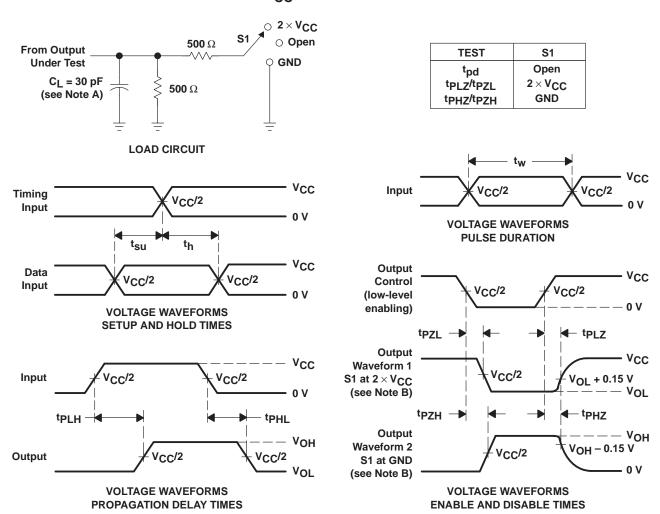


NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \ \Omega$ ,  $t_f \leq$  2 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpl 7 and tpH7 are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms

# PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$



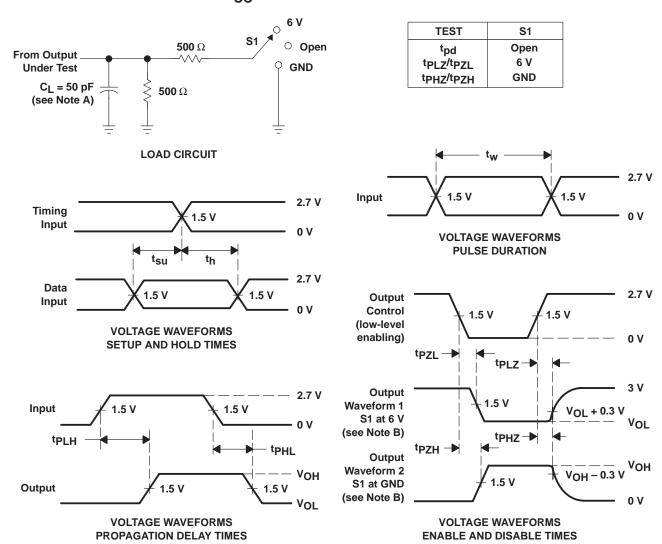
NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z  $_{O}$  = 50  $\Omega$ ,  $t_{f} \leq$  2 ns,  $t_{f} \leq$  2 ns,  $t_{f} \leq$  2 ns,  $t_{f} \leq$  10 mHz, Z  $_{O}$  = 50  $\Omega$ ,  $t_{f} \leq$  10 mHz, Z  $_{O}$
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzl and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 2. Load Circuit and Voltage Waveforms



# PARAMETER MEASUREMENT INFORMATION $V_{CC}$ = 2.7 V AND 3.3 V $\pm$ 0.3 V



NOTES: A. C<sub>I</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq$  2.5 ns.  $t_f \leq$  2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpl 7 and tpH7 are the same as tdis-
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 3. Load Circuit and Voltage Waveforms



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